

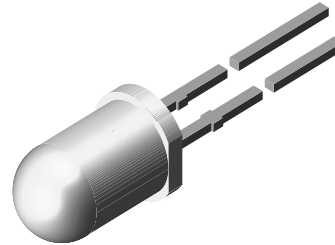
## High Intensity LED, $\varnothing$ 5 mm Tinted Diffused

### Description

This LED contains the double heterojunction (DH) GaAlAs on GaAs technology.

This deep red LED can be utilized over a wide range of drive current. It can be DC or pulse driven to achieve desired light output.

The device is available in a tinted diffused 5 mm package with a wide radiation angle.



19223



### Features

- Exceptional brightness
- Very high intensity even at low drive currents
- Wide viewing angle
- Low forward voltage
- 5 mm (T-1 $\frac{3}{4}$ ) tinted diffused package
- Deep red color
- Categorized for luminous intensity
- Outstanding material efficiency
- Lead-free device

### Applications

- Bright ambient lighting conditions
- Battery powered equipment
- Indoor and outdoor information displays
- Portable equipment
- Telecommunication indicators
- General use

### Parts Table

Part	Color, Luminous Intensity	Angle of Half Intensity ( $\pm\phi$ )	Technology
TLDR5400	Red, $I_V > 35$ mcd	30 °	GaAlAs on GaAs

### Absolute Maximum Ratings

$T_{amb} = 25$  °C, unless otherwise specified

#### TLDR5400

Parameter	Test condition	Symbol	Value	Unit
Reverse voltage		$V_R$	6	V
DC Forward current		$I_F$	50	mA
Surge forward current	$t_p \leq 10$ $\mu$ s	$I_{FSM}$	1	A
Power dissipation	$T_{amb} \leq 65$ °C	$P_V$	100	mW
Junction temperature		$T_j$	100	°C
Operating temperature range		$T_{amb}$	- 40 to + 100	°C
Storage temperature range		$T_{stg}$	- 55 to + 100	°C
Soldering temperature	$t \leq 5$ s, 2 mm from body	$T_{sd}$	260	°C
Thermal resistance junction/ambient		$R_{thJA}$	350	K/W

### Optical and Electrical Characteristics

$T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified

#### Red

#### TLDR5400

Parameter	Test condition	Symbol	Min	Typ.	Max	Unit
Luminous intensity <sup>1)</sup>	$I_F = 20\text{ mA}$	$I_V$	35	70		mcd
Luminous intensity	$I_F = 1\text{ mA}$	$I_V$		3		mcd
Dominant wavelength	$I_F = 20\text{ mA}$	$\lambda_d$		648		nm
Peak wavelength	$I_F = 20\text{ mA}$	$\lambda_p$		650		nm
Spectral line half width		$\Delta\lambda$		20		nm
Angle of half intensity	$I_F = 20\text{ mA}$	$\phi$		$\pm 30$		deg
Forward voltage	$I_F = 20\text{ mA}$	$V_F$		1.8	2.2	V
Reverse current	$V_R = 6\text{ V}$	$I_R$			10	$\mu\text{A}$
Junction capacitance	$V_R = 0, f = 1\text{ MHz}$	$C_j$		30		pF

<sup>1)</sup> in one Packing Unit  $I_{Vmin}/I_{Vmax} \leq 0.5$

### Typical Characteristics ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ unless otherwise specified)

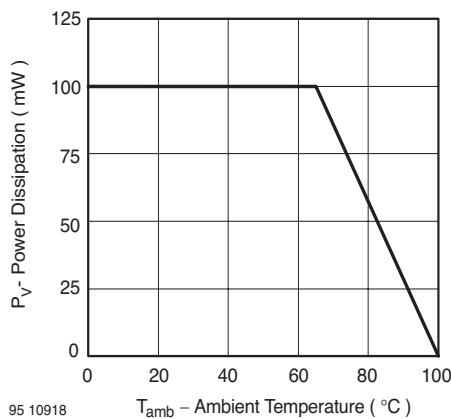


Figure 1. Power Dissipation vs. Ambient Temperature

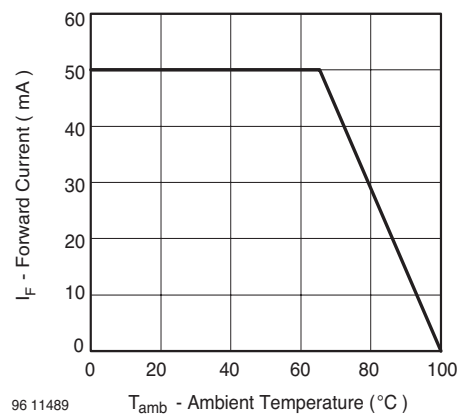


Figure 2. Forward Current vs. Ambient Temperature for AlInGaP

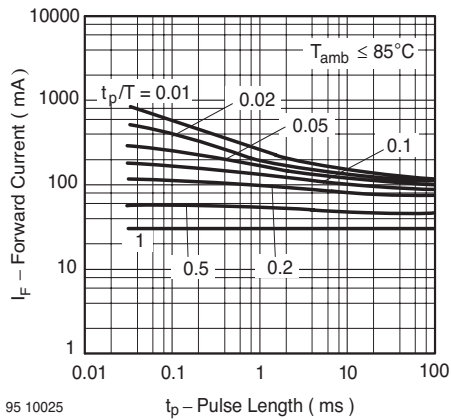


Figure 3. Forward Current vs. Pulse Length

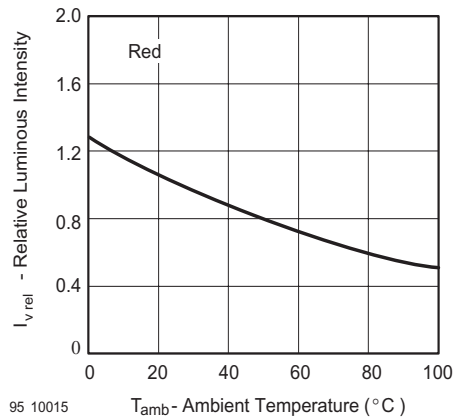


Figure 6. Rel. Luminous Intensity vs. Ambient Temperature

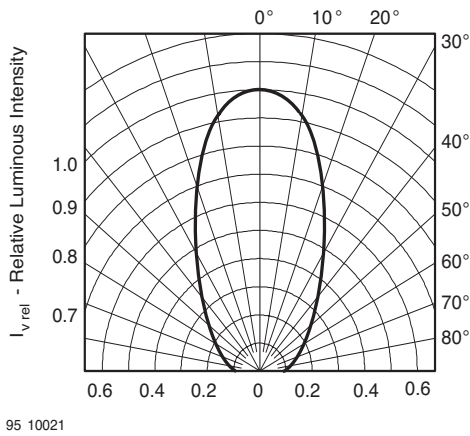


Figure 4. Rel. Luminous Intensity vs. Angular Displacement

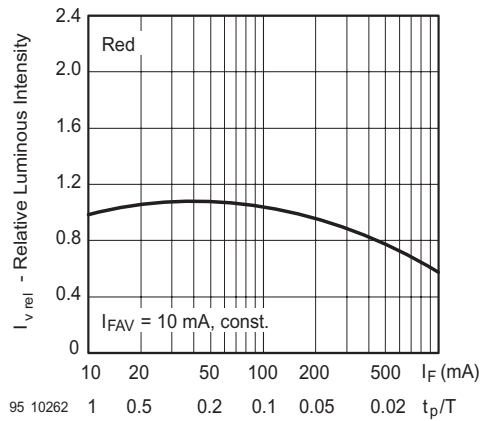


Figure 7. Rel. Lumin. Intensity vs. Forw. Current/Duty Cycle

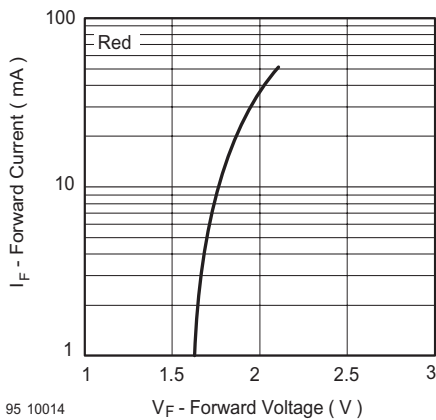


Figure 5.

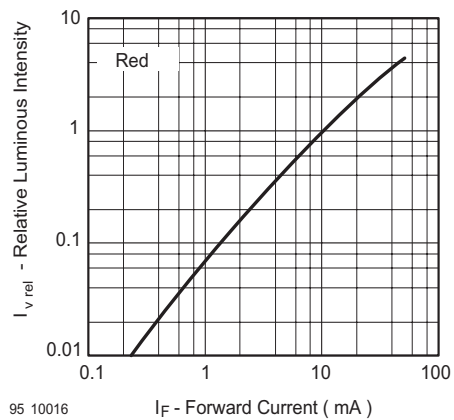


Figure 8. Relative Luminous Intensity vs. Forward Current

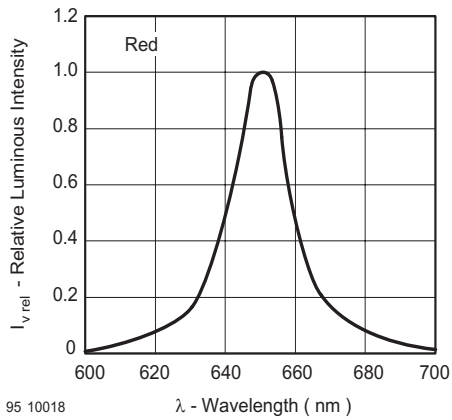
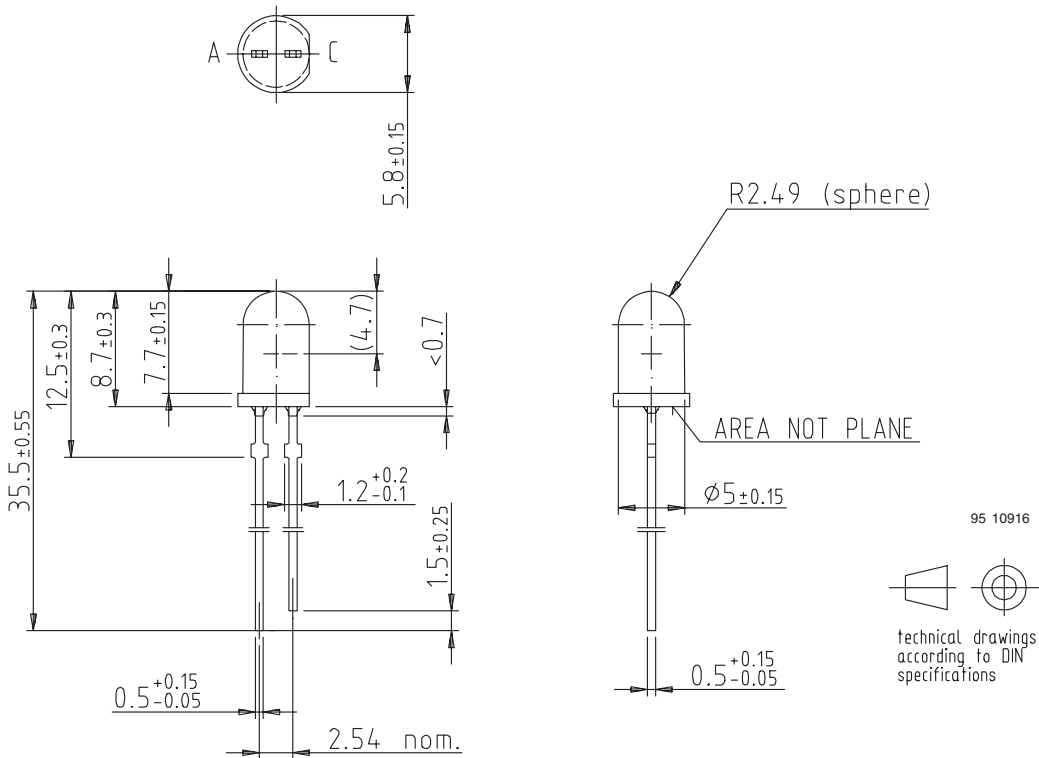


Figure 9. Relative Intensity vs. Wavelength

## Package Dimensions in mm





## **Ozone Depleting Substances Policy Statement**

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1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

**Vishay Semiconductor GmbH** has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

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- Защиту от снятия компонента с производства.
- Оценку стоимости проекта по компонентам.
- Изготовление тестовой платы монтаж и пусконаладочные работы.



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